

PNP SILICON PLANAR MEDIUM POWER DARLINGTON TRANSISTOR

LUCAS INDUSTRIES, INC.

FXT705

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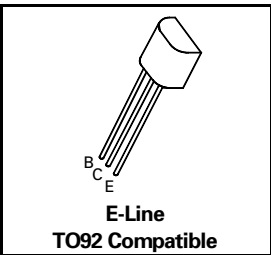
FEATURES

- * 120 Volt V_{CE0}
- * Gain of 3K at $I_C=1$ Amp
- * $P_{tot} = 1$ Watt

APPLICATIONS

- * Lamp, solenoid and relay drivers
- * Replacement of TO126 and TO220 darlington

REFER TO ZTX705 FOR GRAPHS



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	-140	V
Collector-Emitter Voltage	V_{CEO}	-120	V
Emitter-Base Voltage	V_{EBO}	-10	V
Peak Pulse Current	I_{CM}	-4	A
Continuous Collector Current	I_C	-1	A
Power Dissipation at $T_{amb}=25^\circ C$	P_{tot}	1	W
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200	$^\circ C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-140			V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-120			V	$I_C = -10mA, I_B = 0^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-10			V	$I_E = -100\mu A, I_C = 0$
Collector Cut-Off Current	I_{CBO}			-0.1 -10	μA μA	$V_{CB} = -120V, I_E = 0$ $V_{CB} = -120V, T_{amb} = 100^\circ C$
Collector Cut-Off Current	I_{CES}			-10	μA	$V_{CES} = -80V$
Emitter Cut-Off Current	I_{EBO}			-0.1	μA	$V_{EB} = -8V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-1.3 -2.5	V V	$I_C = -1A, I_B = -1mA^*$ $I_C = -2A, I_B = -2mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$			-1.8	V	$I_C = -1A, I_B = -10mA^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$			-1.7	V	$I_C = -1A, V_{CE} = -5V^*$
Static Forward Current Transfer Ratio	h_{FE}	3k 3k 3k 2k		30k		$I_C = -10mA, V_{CE} = -5V^*$ $I_C = -100mA, V_{CE} = -5V^*$ $I_C = -1A, V_{CE} = -5V^*$ $I_C = -2A, V_{CE} = -5V^*$
Transition Frequency	f_T		160		MHz	$I_C = -100mA, V_{CE} = -10V$ $f = 20MHz$